

STRUCTURE Silicon Monolithic Integrated Circuit

PRODUCT SERIES 7-Channel Switching Regulator Controleer for Digital Camera

TYPE BD9749MWV

PIN ASSIGNMENT Fig.1
BLOCK DIAGRAM Fig.1
PACKAGE Fig.2

Functions @1.5V minimum input operating

- Supplies power for the internal circuit by using charge-pump circuit which outputs a voltage twice bigger than VBATvoltage.
   or a equal voltage as VBAT + VIN.
- Contains step-up converter(1ch), step-down converter(1ch), cross converter(1ch), configurable for step-up/step-down converter(2ch).
- ■Contains 4FETs for the cross converter channe.
- ●3channels contain transistor for synchronous rectifying action mode.
- Contains a FET for step-up converter for CCD.
- ALL channels contain internal compensation between inputs outputs of error amps.
- Contains sequence control circuit for ch2,3 and 4. Sequence for ch5 and 6 are configurable for two types.
- Two channels have high side switches with soft start function.
- ●Two channels have PMOS back gate control circuit.
- Othermally enhanced QFN48 package.(7mm x 7mm, 0.4mm pitch)

#### OAbsolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Units	
Power Supply Boltage	VBAT	<b>−0.3~7</b>	V	
	VHx1~4	<b>−0.3~7</b>	٧	
Power Input Voltage	HS6H,HS7H	<b>−0.3~7</b>	V	
Fower input voitage	VLx6	<b>−0.3~18</b>	V	
	VIN	-0.3∼7	V	
	IomaxLx1	±12	A	
	IomaxHx2	±1.5	Α	
Output Current	IomaxHx3∼4	±12	Α	
	IomaxHS6∼7	±12	Α	
	IomaxLx6	±0.8	Α	
Power Dissipation	Pd	0.60 *1	W	
Operating Temperature	Topr	<b>−25~+85</b>	°C	
Storage Temperature	Tstg	<b>−55~+150</b>	°C	
Junction Tempareture	Tjmax	+150	°C	

<sup>(\*1)</sup> Without external heat sink, the power dissipation reduces by 4.8mW/°C over 25°C.

# ORecommended operating conditions

Parameter	Symbol	Spec			Unit
	Symbol	MIN	TYP	MAX	Unit
Power Supply Voltage	VBAT	1.5		5.5	٧
VREF Pin Connecting Capacitor	CVREF	0.47	1.0	4.7	μF
VREGA Pin Connecting Capacitor	CVREGA	0.47	1.0	4.7	μF
SCP Pin Connecting Capacitor	CSCP		_	0.47	μF
C+H to C+L connecting Capacitor	CF	1.0	_	-	μF
[Oscillator]					
Oscillator Frequency	fosc	0.6	12	1.5	MHz
OSC Timing Resistor	RT	47	62	120	kΩ

Status of this document

The Japanese version of this document is the official specification. Please use the translation version of this document as a reference to expedite understanding of the official version. If these are any uncertainty in translation version of this document, official version takes priority.



OElectrical characteristics (Ta=25°C, VBAT=3V, RT=62k, STB1~7=3V)

		S	tandard valu	ne.			
Parameter	Symbol	MIN	TYP	MAX	Units	Conditions	
[Change Pump Circuit]							
Output Voltage (Regulated)	Vcpout1	52	5.4	1	٧	io=1mA, INV1~7=1.2V NON5=-0.2V	
Output Voltage (X2 Step up)	Vopout2	4.5	4.8	1	>	Only for internal Current VBAT=2.5V, INV1~7=1.2V NON5=-0.2V	
Output Resistance	Vapro	_	35	50	Ω	OF=1 μF, VBAT=25V	
Operating Frequency	fcp	60	75	90	kHz	RT=62kΩ	
Minimum VBAT Voltage	Vst1	1.5	-	-	<b>&gt;</b>		
(Internal Regulator V							
Output Voltage	VREGA	24	25	2.6		lo=5mA	
Prevention Circuit of		on by Low v					
Threshold Voltage	Vstd1	_	215	230	٧	VREGA Monitor	
Hysteresis Width		50	100	200	mA		
(Short Circuit Protes	ction]						
SCP Stand by	\/e		20	170			
Voltage SCP Out Source	Vssc		22		mV		
Current SOP Threshold	Iscp	2	4	6	μА	Vsqp=0.1V	
Voltage [Oscillator]	Vsap	0.9	1.0	1,1	٧		
Frequency		l					
CH1~4 Frequency	fosc1	1.0	1.2	1,4	MHz	RT=62kΩ	
CH5~7 Max Duty	fosc2	0.5	0,6	0.7	MHz	RT=62kΩ	
1,3,4 (Step Down) Max Duty	Dmax1d	_	_	100	- 5	Vsap=0V ※	
1,4 (Step Up) Max Duty 5,6,7	Dmax1u Dmax2	86 86	92 92	96 96	%		
Max Duty	Dillaz	-	32	- 50			
CH2 LX21	Dmax3			100	*		
Max Duty CH2 LX22	Dmax4	78	84	90	*		
[Error AMP]							
Input Bias Current	<b>■N</b> V		0	50	nA	INV1~7, NON5=3.0V	
INV Threshold Voltage1	VINV1	0.79	0.80	0.81	٧	CH1~4	
INV Threshold Voltage2	VINV2	0.99	1.00	1.01	٧	CH6,7V	
INV Threshold Voltage3	V <b>I</b> NV3	380	400	420	mV	СН71	
(Base Bias Voltage	Vief for inverte	d Channel]					
CH5 OutputVoltage	VOUT5	-6.09	-6.00	-5.91	٧	NON5 resistor12kΩ, 72kΩ	
Line Regulation	DVLi		4.0	125	mV	CPOUT=1.5~5.5V	
Load Regulation	DVLo	-	1.0	7.5	mV	iref=10uA~100uA	
Output Current When shorted	los	0.2	1,0	-	mA	Vref=0V	
[Soft Start]							
CH124 Soft Start Time	Tss1	3.4	4.4	5.4	msec	RT=62kΩ	
CH3 Soft Start Time	Tss2	1.2	22	3.2	msec	RT=62kΩ	
CH5 Soft Start Time	Tss3	3.4	4.4	5,4	msec	RT=62kΩ	
CH6,7 Soft Start Time	Tss4	4.4	5.5	6.6	msec	RT=62kΩ	

Characterist et a							
Parameter		Symbol	Min	tandard valu	MAX	Units	Conditions
[Output Drive	[Output Driver]						
CH1 Highside		RON1P	_	280	380	mΩ	HX1=5V
ON Resistano							
	OH1 Lowside SW ON Resistance		-	120	180	mΩ	CPOUT=5.4V
CH2 LX21 端							
Highside SW		RON21P	_	160	240	mΩ	HX2=3.0V,
ON Resistano	æ						CPOUT=5.4V
CH2 LX21Pir	1						
Lowside SW		RON21N	_	130	200	mΩ	CPOUT=5,4V
ON Resistano CH2 LX22Pir							
Highside SW	•	RON22P	_	180	280	mΩ	VOUT2=5.0V
ON Resistano	æ						
CH2 LX22Pir	1						
Lowside SW		RON22N	-	130	200	mΩ	CPOUT=5.4V
ON Resista CH3 Highside		-			_		HX3=3.0V.
ON Resistant		RON3P	_	160	260	mΩ	CPOUT=5.4V
CH3 Lowside		DONIA.		120			
ON Resistano	œ	RON3N		130	200	mΩ	CPOUT=5.4V
CH4 Highside		RON4P	_	280	380	mΩ	HX4=5.0V
ON Resistano							
OH4 Lowside ON Resistant		RON4N	_	130	200	mΩ	CPOUT=5.4V
CH6 NMOS							
ON抵抗		RON6N	-	400	700	mΩ	CPOUT=5,4V
CH6,7 Load S		RON67P	_	200	300	mΩ	HS6H,HS7H=3.0V
ON Resistano	ж	11011011					CPOUT=5.4V
CH5 Driver	U	Vout5H	-	PVCC5 -1.5	_	v	
CH5 Driver	Output Voltage H						
1	Output Voltage L		-	0.5	1,0	V	
OUT7 Driver		Vout7H		орол	_	v	
Output Volta	ge H	VOUC/FI		-1.5			
OUT7 Driver		Vout7L	-	0.5	1.0	v	
Output Volta	ge L onfigure step up	/down Switch	to confin	000	1		
			CPOUT	CODSeq		· .,	
UDSEL1.4 Control	Step down	VUDDO	×0.7	_	ороит	٧	
Voltage	Stepup	VUDUP	0	ı —	OPOUT ×03	V	
COD SEQ	with	VSEQG	0	_	CPOUT	v	
Control	sequence without		СРОЛТ	-	×0.3	-	
Voltage	sequence	VSEQV	×07	_	CPOUT	٧	
[STB1~7]							
STB	Active	VSTBH1	1.5	-	5.5	٧	
Voltage	Non Active	VSTBL1	-0.3	_	0.3	٧	
STB1 Pin		RSTB1	150	240	350	kΩ	
Pull down Re		1					
STB234, 56, 1 Pull down Re		RSTB2	250	400	700	kΩ	
Circuit Cum			L	L			
	VBAT	ISTB1	l _		5	μΔ	
	terminal	NIDI			,	μА	
Stand-by	HX terminal	ISTB2	-	-	5	μА	Step-down UDSEL1,4=CPOUT
Current	LX terminal	ISTB3	_		5	μА	Step-up UDSEL1,#0V
	HS67H	ISTB4	_	_	5	μА	
Circuit Comm	Circuit Current1		<del> </del>	-	<u> </u>	<u> </u>	
	(VBAT current		]				IN/1~7=1.2V.
	when voltage supplied		-	7.0	11.0	mA	NON5=-02V, VBAT=3.0V
for the termin							
Circuit Curre							IN/1~7=12V.
(CPOUT cur when voltage		lcc2	-	3.0	5.0	mA.	NON5=-0.2V, CPOUT=5.4V
for the termin							C+H, C+L=OPEN
JIG 00/118							l .

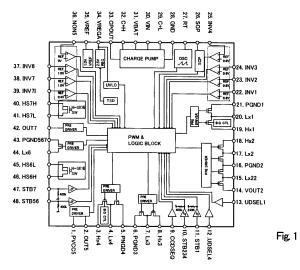
<sup>©</sup>This product is not designed for normal operation with in a radioactive environment

<sup>%</sup>The protective circuit start working when circuit is operated by 100% duty.

So it is possible to use only for transition time shorter than charge time for SCP.



# OPin Assignment •Block Diagram

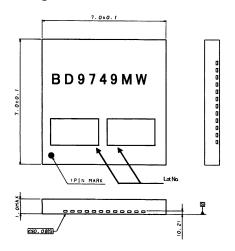


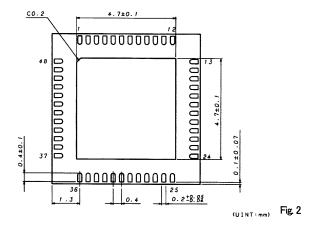
**OPin Description** 

Pin Name	Description		
VBAT	Input for battery boltage		
VIN	Peturning voltage from output terminal		
CPOUT	Output terminal for Charge Pump		
GND	Ground terminal		
C+H	Terminal for connecting flying capasitor		
0111	for Charege Pump (H side)		
C+L	Terminal for connecting flying capasitor		
0.2	for Charege Pump (L side)		
PGND1,2,3,4,567	Ground terminal for internal FET		
VREGA	VREGA output		
VREF	CH5 base bias voltage		
PVCC5	CH5 PMOS VCC input for driver		
OUT5	Terminal for connecting gate of CH5 PMOS		
OUT7	Terminal for connecting gate of CH7 NMOS		
Hx1,3,4	Input terminal for synchronous High side		
11x1,0,4	switch, Power supply for Pch Driver		
Lx1,346	Terminal for connecting inductors		
H⁄2	Power supply for channel 2		

PinName	Description				
Lx21	Terminal for connecting inductor for CH2 input				
Lx22	Terminal for connecting inductor for CH2 output				
VOUT2	CH2 output voltage				
HS6H,HS7H	Power supply for internal load switch				
HS6L,HS7L	Output terminal for internal load switch				
INV1,2,3,4,6,7	Error AMP inverted input				
NON5	Error AMP non-inverted input				
INV7I	Error AMP inverted input				
RT	For connecting a resistor				
101	to set the OSC frequency				
SCP	for connecting a capacitor				
307	to set up the delay time of the SCP				
UDSEL1.4	Step-up/down switching mode selection				
ODOLLI,4	(H: step-down / L: step-up)				
STB1.234.7.56	ON/OFF switch				
3121,204,7,00	H: Operating over 1.5V				
}	Terminal for setting CCD sequence				
CCDSEQ	(H: Independent,				
	L: Inverted channel starts after step-up starts)				

# **OPackage**





REV. B



#### Operation Notes

## 1.) Absolute maximum ratings

This product is produced with strict quality control. However, the IC may be destroyed if operated beyond its absolute maximum ratings. If the device is destroyed by exceeding the recommended maximum ratings, the failure mode will be difficult to determine. (E.g. short mode, open mode) Therefore, physical protection counter-measures (like fuse) should be implemented when operating conditions beyond the absolute maximum ratings anticipated.

## 2.) GND potential

Make sure GND is connected at lowest potential. All pins except NON5, must not have voltage below GND. Also, NON5 pin must not have voltage below - 0.3V on start up.

### 3.) Setting of heat

Make sure that power dissipation does not exceed maximum ratings.

### 4.) Pin short and mistake fitting

Avoid placing the IC near hot part of the PCB. This may cause damage to IC. Also make sure that the output-to-output and output to GND condition will not happen because this may damage the IC.

## 5.) Actions in strong magnetic field

Exposing the IC within a strong magnetic field area may cause malfunction.

#### 6.) Mutual impedance

Use short and wide wiring tracks for the main supply and ground to keep the mutual impedance as small as possible. Use inductor and capacitor network to keep the ripple voltage minimum.

### 7.) Voltage of STB pin

The threshold voltages of STB pin are 0.3V and 1.5V. STB state is set below 0.3V while action state is set beyond 1.5V. The region between 0.3V and 1.5V is not recommended and may cause improper operation.

The rise and fall time must be under 10msec. In case to put capacitor to STB pin, it is recommended to use under 0.01 µF.

#### 8.) Thermal shutdown circuit (TSD circuit)

The IC incorporates a built-in thermal shutdown circuit (TSD circuit). The thermal shutdown circuit (TSD circuit) is designed only to shut the IC off to prevent runaway thermal operation. It is not designed to protect the IC or guarantee its operation. Do not continue to use the IC after operating this circuit or use the IC in an environment where the operation of this circuit is assumed.

## 9.) Rush current at the time of power supply injection.

An IC which has plural power supplies, or CMOS IC could have momentary rush current at the time of power supply injection. Please take care about power supply coupling capacity and width of power Supply and GND pattern wiring.

#### 1 0.)IC Terminal Input

This IC is a monolithic IC that has a P- board and P+ isolation for the purpose of keeping distance between elements. A P-N junction is formed between the P-layer and the N-layer of each element, and various types of parasitic elements are then formed. For example, an application where a resistor and a transistor are connected to a terminal (shown in Fig.15):

- OWhen GND > (terminal A) at the resistor and GND > (terminal B) at the transistor (NPN), the P-N junction operates as a parasitic diode.
- When GND > (terminal B) at the transistor (NPN), a parasitic NPN transistor operates as a result of the NHayers of other elements in the proximity of the aforementioned parasitic diode.

Parasitic elements are structurally inevitable in the IC due to electric potential relationships. The operation of parasitic elements Induces the interference of circuit operations, causing malfunctions and possibly the destruction of the IC. Please be careful not to use the IC in a way that would cause parasitic elements to operate. For example, by applying a voltage that is lower than the GND (P-board) to the input terminal.

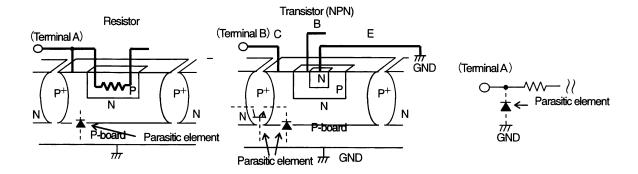


Fig - 3 Simplified structure of a Bipolar IC

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Appendix1-Rev2.0